

**FEATURES**

**USB 2.0 (480 Mbps) and USB 1.1 (12 Mbps) signal switching compliant**  
**Tiny 10-lead 1.6 mm × 1.3 mm mini LFCSP package and 12-lead 3 mm × 3 mm LFCSP package**  
**2.7 V to 3.6 V single-supply operation**  
**Typical power consumption: <0.1 μW**  
**RoHS compliant**

**APPLICATIONS**

**USB 2.0 signal switching circuits**  
**Cellular phones**  
**PDA's**  
**MP3 players**  
**Battery-powered systems**  
**Headphone switching**  
**Audio and video signal routing**  
**Communications systems**

**GENERAL DESCRIPTION**

The ADG772 is a low voltage CMOS device that contains two independently selectable single-pole, double throw (SPDT) switches. It is designed as a general-purpose switch and can be used for routing both USB 1.1 and USB 2.0 signals.

This device offers a data rate of 1260 Mbps, making the part suitable for high frequency data switching. Each switch conducts equally well in both directions when on and has an input signal range that extends to the supplies. The ADG772 exhibits break-before-make switching action.

The ADG772 is available in a 12-lead LFCSP and a 10-lead mini LFCSP. These packages make the ADG772 the ideal solution for space-constrained applications.

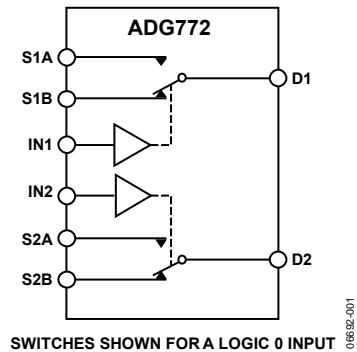
**FUNCTIONAL BLOCK DIAGRAM**

Figure 1.

**PRODUCT HIGHLIGHTS**

1. 1.6 mm × 1.3 mm mini LFCSP package.
2. USB 1.1 (12 Mbps) and USB 2.0 (480 Mbps) compliant.
3. Single 2.7 V to 3.6 V operation.
4. 1.8 V logic compatible.
5. RoHS compliant.

**Rev. A**

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## REVISION HISTORY

### 6/08—Rev. 0 to Rev. A

Changes to Product Highlights.....	1
Changes to Input High Voltage, $V_{INH}$ , Parameter.....	3

### 8/07—Revision 0: Initial Version

## SPECIFICATIONS

$V_{DD} = 2.7\text{ V to }3.6\text{ V}$ ,  $GND = 0\text{ V}$ , unless otherwise noted.

**Table 1.**

Parameter	+25°C	−40°C to +85°C	Unit	Test Conditions/Comments
<b>ANALOG SWITCH</b>				
Analog Signal Range		0 V to $V_{DD}$	V	
On-Resistance ( $R_{ON}$ )	6.7		$\Omega$ typ	$V_{DD} = 2.7\text{ V}$ , $V_S = 0\text{ V to }V_{DD}$ , $I_{DS} = 10\text{ mA}$ ; see Figure 21
		8.8	$\Omega$ max	
On-Resistance Match Between Channels ( $\Delta R_{ON}$ )	0.04		$\Omega$ typ	$V_{DD} = 2.7\text{ V}$ , $V_S = 1.5\text{ V}$ , $I_{DS} = 10\text{ mA}$
		0.2	$\Omega$ max	
On Resistance Flatness ( $R_{FLAT(ON)}$ )	3.3		$\Omega$ typ	$V_{DD} = 2.7\text{ V}$ , $V_S = 0\text{ V to }V_{DD}$ , $I_{DS} = 10\text{ mA}$
		3.6	$\Omega$ max	
<b>LEAKAGE CURRENTS</b>				
Source Off Leakage $I_S$ (Off)	$\pm 0.2$		nA typ	$V_{DD} = 3.6\text{ V}$ $V_S = 0.6\text{ V}/3.3\text{ V}$ , $V_D = 3.3\text{ V}/0.6\text{ V}$ ; see Figure 22
Channel On Leakage $I_D$ , $I_S$ (On)	$\pm 0.2$		nA typ	$V_S = V_D = 0.6\text{ V or }3.3\text{ V}$ ; see Figure 23
<b>DIGITAL INPUTS</b>				
Input High Voltage, $V_{INH}$		1.35	V min	
Input Low Voltage, $V_{INL}$		0.8	V max	
Input Current, $I_{INL}$ or $I_{INH}$	0.005		$\mu\text{A}$ typ	$V_{IN} = V_{INL}$ or $V_{INH}$
		$\pm 0.1$	$\mu\text{A}$ max	$V_{IN} = V_{INL}$ or $V_{INH}$
Digital Input Capacitance, $C_{IN}$	2		pF typ	
<b>DYNAMIC CHARACTERISTICS<sup>1</sup></b>				
$t_{ON}$	9		ns typ	$R_L = 50\ \Omega$ , $C_L = 35\text{ pF}$
	12.5	13.5	ns max	$V_S = 2\text{ V}$ ; see Figure 24
$t_{OFF}$	6		ns typ	$R_L = 50\ \Omega$ , $C_L = 35\text{ pF}$
	9.5	10	ns max	$V_S = 2\text{ V}$ ; see Figure 24
Propagation Delay	250		ps typ	$R_L = 50\ \Omega$ , $C_L = 35\text{ pF}$
Propagation Delay Skew, $t_{SKEW}$	20		ps typ	$R_L = 50\ \Omega$ , $C_L = 35\text{ pF}$
Break-Before-Make Time Delay ( $t_{BBM}$ )	5		ns typ	$R_L = 50\ \Omega$ , $C_L = 35\text{ pF}$
	3.4	2.9	ns min	$V_{S1} = V_{S2} = 2\text{ V}$ ; see Figure 25
Charge Injection	0.5		pC typ	$V_D = 1.25\text{ V}$ , $R_S = 0\ \Omega$ , $C_L = 1\text{ nF}$ ; see Figure 26
Off Isolation	73		dB typ	$R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ , $f = 1\text{ MHz}$ ; see Figure 27
Channel-to-Channel Crosstalk	−90		dB typ	S1A to S2A/S1B to S2B; $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ , $f = 1\text{ MHz}$ ; see Figure 28
	−80		dB typ	S1A to S1B/S2A to S2B; $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ , $f = 1\text{ MHz}$ ; see Figure 29
−3 dB Bandwidth	630		MHz typ	$R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ ; see Figure 30
Data Rate	1260		Mbps typ	$R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ ; see Figure 30
$C_S$ (Off)	2.4		pF typ	
$C_D$ , $C_S$ (On)	6.9		pF typ	
<b>POWER REQUIREMENTS</b>				
$I_{DD}$	0.006		$\mu\text{A}$ typ	$V_{DD} = 3.6\text{ V}$ Digital inputs = 0 V or 3.6 V
		1	$\mu\text{A}$ max	

<sup>1</sup> Guaranteed by design, not subject to production test.

## ABSOLUTE MAXIMUM RATINGS

T<sub>A</sub> = 25°C, unless otherwise noted.

Table 2.

Parameter	Rating
V <sub>DD</sub> to GND	−0.3 V to +4.6 V
Analog Inputs, <sup>1</sup> Digital Inputs	−0.3 V to V <sub>DD</sub> + 0.3 V or 10 mA, whichever occurs first
Peak Current, Pin S1A, Pin S2A, Pin D1, or Pin D2	100 mA (pulsed at 1 ms, 10% duty cycle max)
Continuous Current, Pin S1A, Pin S2A, Pin D1, or Pin D2	30 mA
Operating Temperature Industrial Range (B Version)	−40°C to +85°C
Storage Temperature Range	−65°C to +150°C
Junction Temperature	150°C
θ <sub>JA</sub> Thermal Impedance (4-Layer Board)	
10-Lead Mini LFCSP	131.6°C/W
12-Lead LFCSP	61°C/W
Pb-Free Temperature, Soldering, IR Reflow	
Peak Temperature	260(+0/−5)°C
Time at Peak Temperature	10 sec to 40 sec

<sup>1</sup> Overvoltages at the IN1, IN2, S1A, S2A, D1, or D2 pin are clamped by internal diodes. Current should be limited to the maximum ratings given.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Only one absolute maximum rating can be applied at any one time.

### ESD CAUTION



**ESD (electrostatic discharge) sensitive device.** Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

# PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

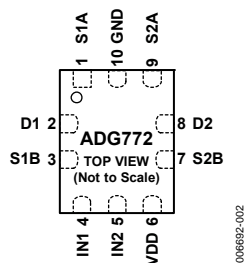


Figure 2. 10-Lead Mini LFCSP Pin Configuration

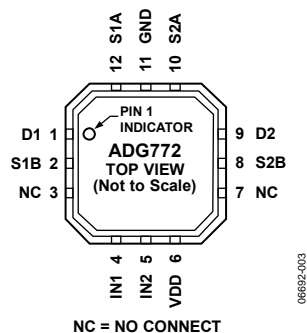


Figure 3. 12-Lead LFCSP Pin Configuration

Table 3. Pin Function Descriptions

Pin No.		Mnemonic	Description
10-Lead Mini LFCSP	12-Lead LFCSP		
1	12	S1A	Source Terminal. Can be an input or an output.
2	1	D1	Drain Terminal. Can be an input or an output.
3	2	S1B	Source Terminal. Can be an input or an output.
4	4	IN1	Logic Control Input. This pin controls Switch S1A and Switch S1B to D1.
5	5	IN2	Logic Control Input. This pin controls Switch S2A and Switch S2B to D2.
6	6	VDD	Most Positive Power Supply Potential.
7	8	S2B	Source Terminal. Can be an input or an output.
8	9	D2	Drain Terminal. Can be an input or an output.
9	10	S2A	Source Terminal. Can be an input or an output.
10	11	GND	Ground (0 V) Reference.
N/A	3, 7	NC	No Connect.

## TRUTH TABLE

Table 4.

Logic (IN1 or IN2)	Switch A (S1A or S2A)	Switch B (S1B or S2B)
0	Off	On
1	On	Off

## TYPICAL PERFORMANCE CHARACTERISTICS

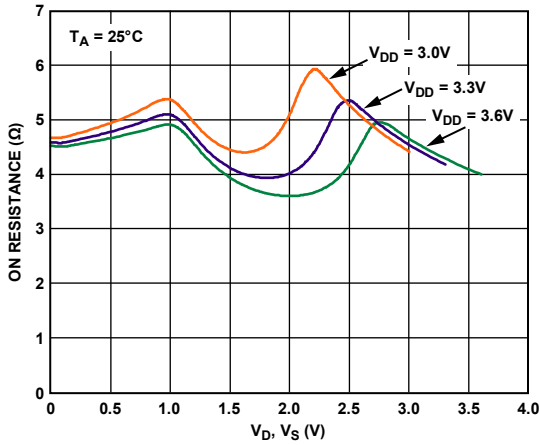


Figure 4. On Resistance vs.  $V_D$ ,  $V_S$ ;  $V_{DD} = 3.3\text{ V} \pm 0.3\text{ V}$

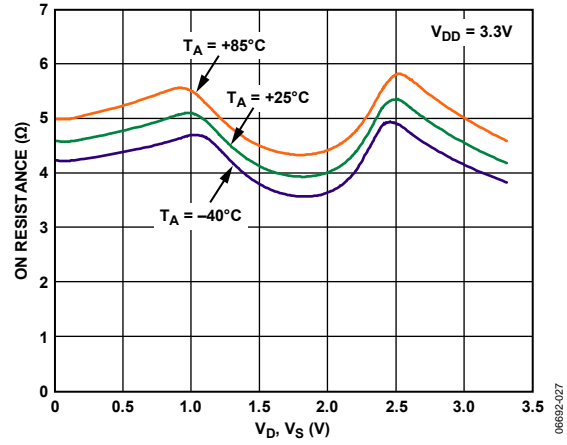


Figure 7. On Resistance vs.  $V_D$ ,  $V_S$  for Different Temperatures;  $V_{DD} = 3.3\text{ V}$

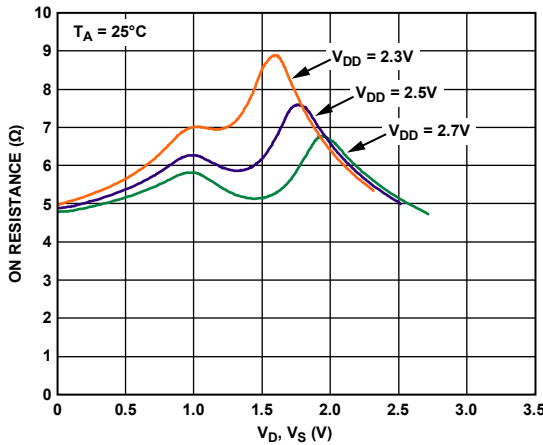


Figure 5. On Resistance vs.  $V_D$ ,  $V_S$ ;  $V_{DD} = 2.5\text{ V} \pm 0.2\text{ V}$

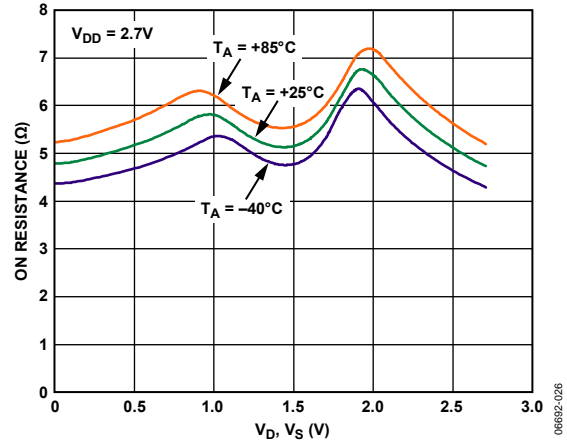


Figure 8. On Resistance vs.  $V_D$ ,  $V_S$  for Different Temperatures;  $V_{DD} = 2.7\text{ V}$

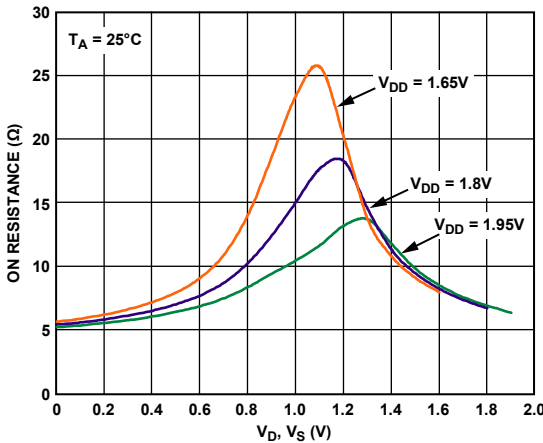


Figure 6. On Resistance vs.  $V_D$ ,  $V_S$ ;  $V_{DD} = 1.8\text{ V} \pm 0.15\text{ V}$

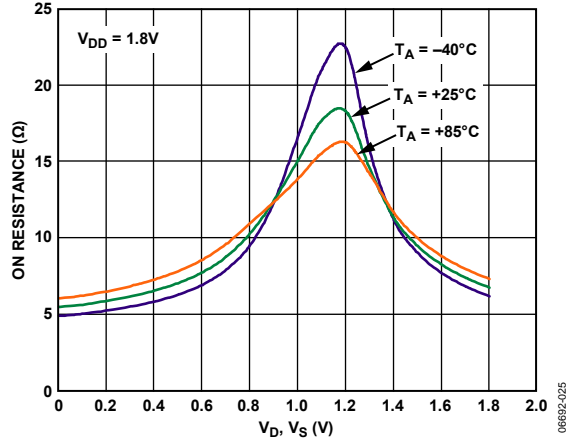


Figure 9. On Resistance vs.  $V_D$ ,  $V_S$  for Different Temperatures;  $V_{DD} = 1.8\text{ V}$

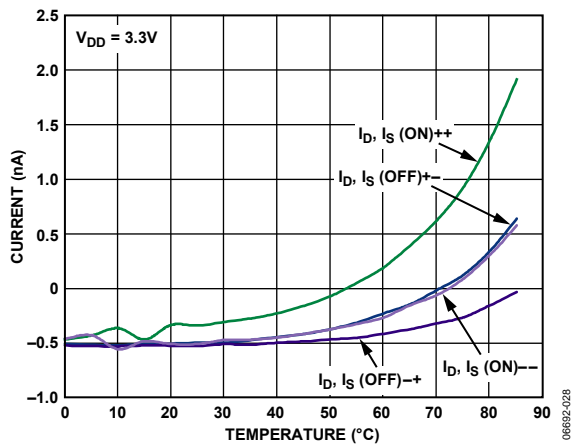


Figure 10. Leakage Current vs. Temperature;  $V_{DD} = 3.3V$

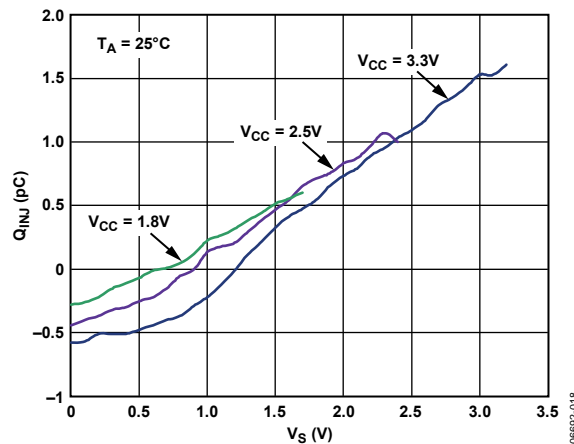


Figure 13. Charge Injection vs. Source Voltage

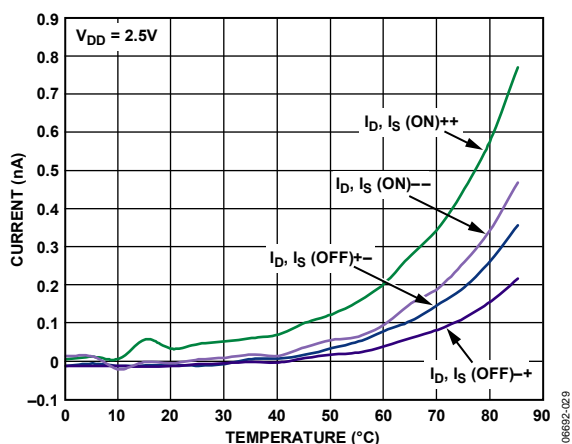


Figure 11. Leakage Current vs. Temperature;  $V_{DD} = 2.5V$

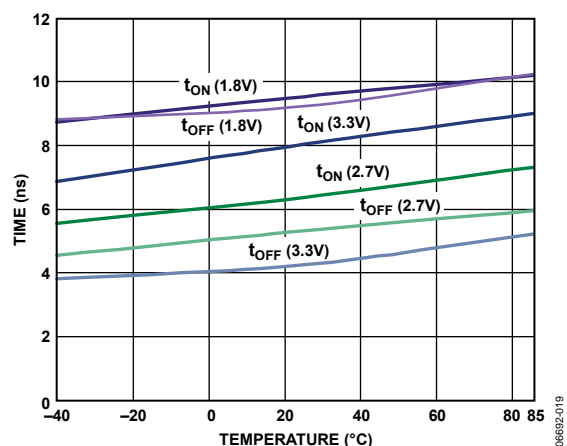


Figure 14.  $t_{ON}/t_{OFF}$  Times vs. Temperature

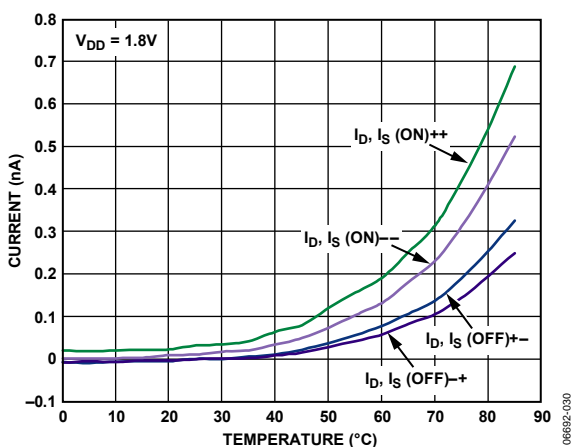


Figure 12. Leakage Current vs. Temperature;  $V_{DD} = 1.8V$

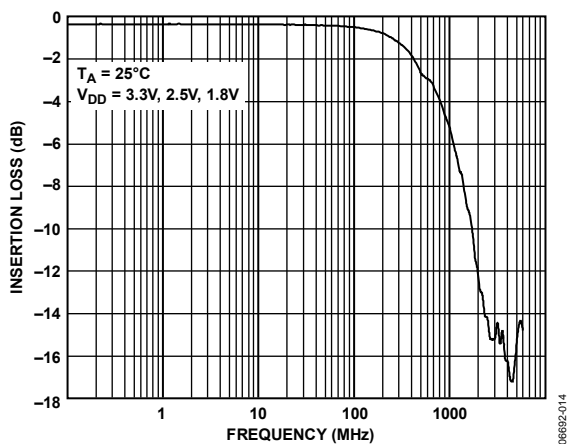


Figure 15. Bandwidth

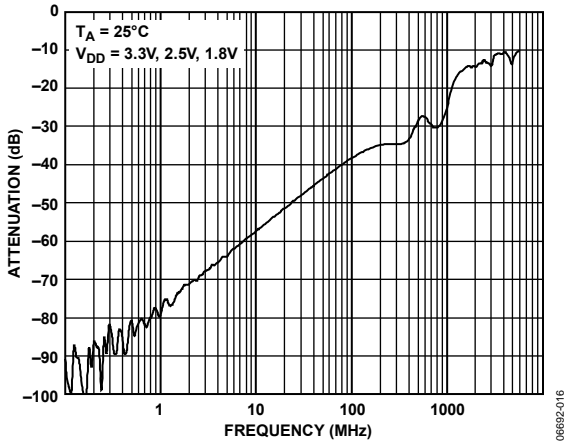


Figure 16. Off Isolation vs. Frequency

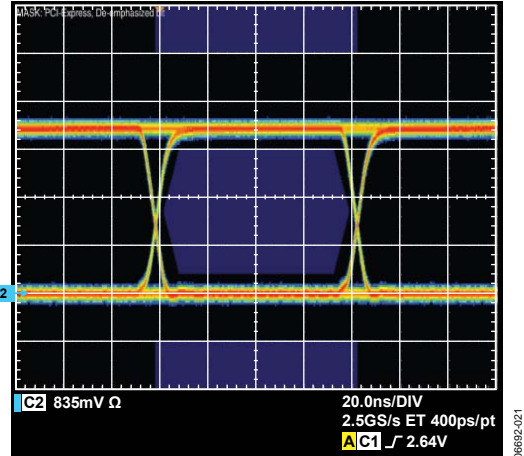


Figure 19. USB 1.1 Eye Diagram

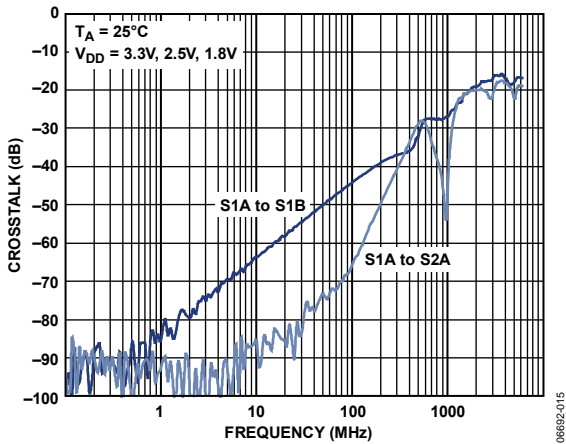


Figure 17. Crosstalk vs. Frequency

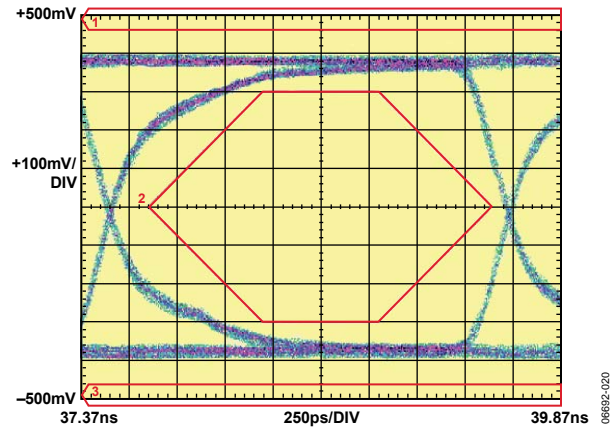


Figure 20. USB 2.0 Eye Diagram

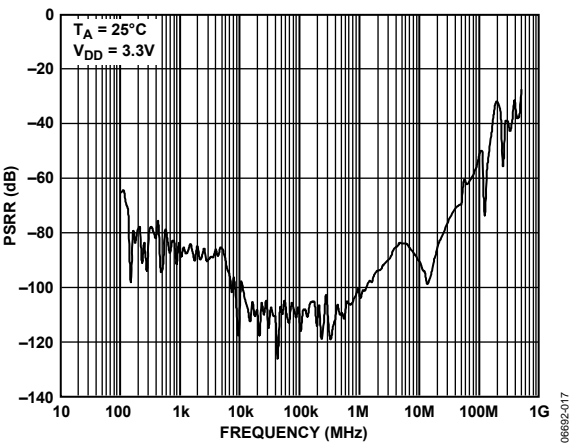


Figure 18. PSRR vs. Frequency



# TEST CIRCUITS

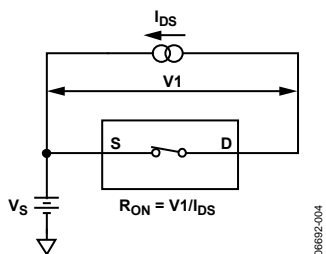


Figure 21. On Resistance

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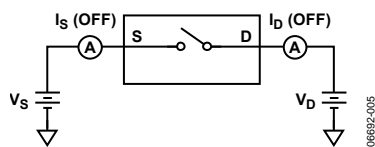


Figure 22. Off Leakage

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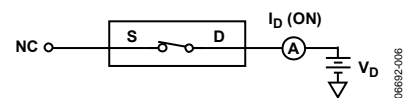


Figure 23. On Leakage

06692-006

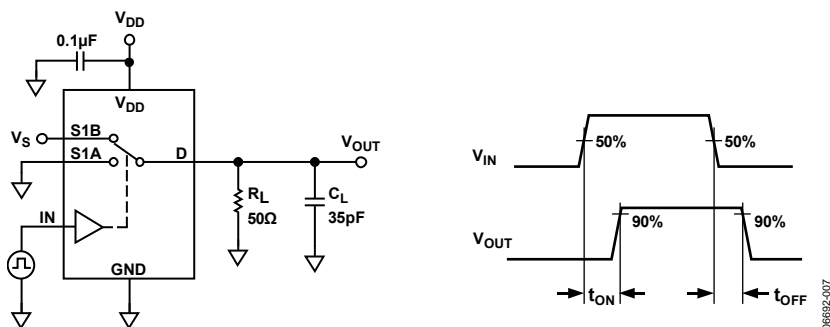


Figure 24. Switching Times,  $t_{ON}$ ,  $t_{OFF}$

06692-007

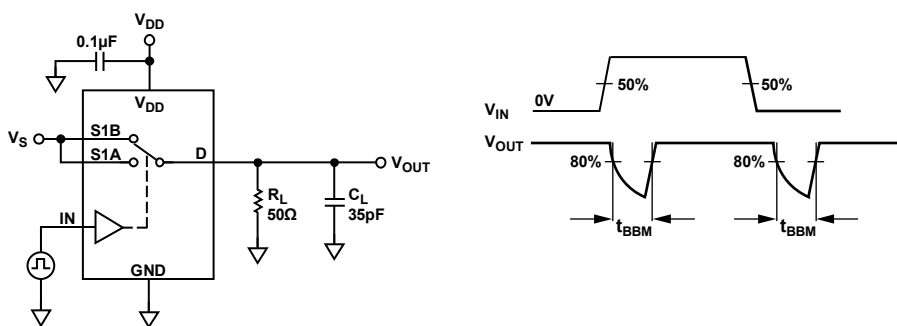


Figure 25. Break-Before-Make Time Delay,  $t_{BBM}$

06692-008

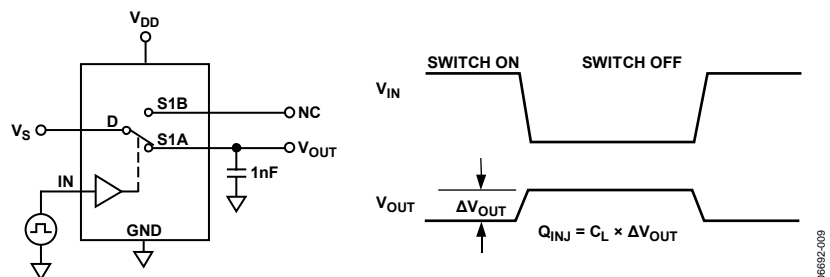


Figure 26. Charge Injection

06692-009

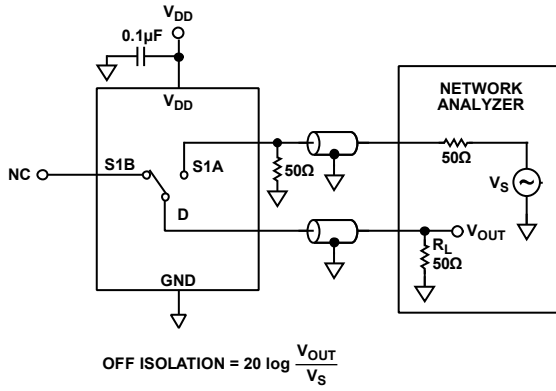


Figure 27. Off Isolation

06692-010

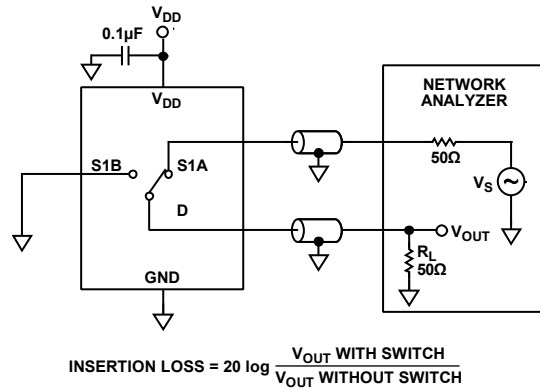


Figure 29. Channel-to-Channel Crosstalk (S1A to S1B)

06692-012

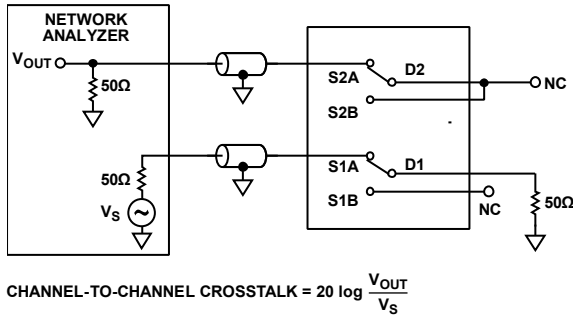


Figure 28. Channel-to-Channel Crosstalk (S1A to S2A)

06692-013

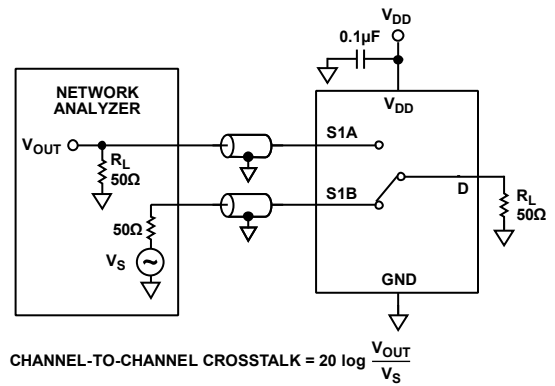


Figure 30. Bandwidth

06692-011

## TERMINOLOGY

**I<sub>DD</sub>**

Positive supply current.

**V<sub>D</sub>, V<sub>S</sub>**

Analog voltage on Terminal D and Terminal S.

**R<sub>ON</sub>**

Ohmic resistance between Terminal D and Terminal S.

**R<sub>FLAT</sub> (On)**

The difference between the maximum and minimum values of on resistance as measured on the switch.

**ΔR<sub>ON</sub>**

On resistance match between any two channels.

**I<sub>S</sub> (Off)**

Source leakage current with the switch off.

**I<sub>D</sub> (Off)**

Drain leakage current with the switch off.

**I<sub>D</sub>, I<sub>S</sub> (On)**

Channel leakage current with the switch on.

**V<sub>INL</sub>**

Maximum input voltage for Logic 0.

**V<sub>INH</sub>**

Minimum input voltage for Logic 1.

**I<sub>INL</sub>, I<sub>INH</sub>**

Input current of the digital input.

**C<sub>S</sub> (Off)**

Off switch source capacitance. Measured with reference to ground.

**C<sub>D</sub> (Off)**

Off switch drain capacitance. Measured with reference to ground.

**C<sub>D</sub>, C<sub>S</sub> (On)**

On switch capacitance. Measured with reference to ground.

**C<sub>IN</sub>**

Digital input capacitance.

**t<sub>ON</sub>**

Delay time between the 50% and 90% points of the digital input and switch on condition.

**t<sub>OFF</sub>**

Delay time between the 50% and 90% points of the digital input and switch off condition.

**t<sub>BBM</sub>**

On or off time measured between the 80% points of both switches when switching from one to another.

**Charge Injection**

Measure of the glitch impulse transferred from the digital input to the analog output during on/off switching.

**Off Isolation**

Measure of unwanted signal coupling through an off switch.

**Crosstalk**

Measure of unwanted signal that is coupled from one channel to another as a result of parasitic capacitance.

**-3 dB Bandwidth**

Frequency at which the output is attenuated by 3 dB.

**On Response**

Frequency response of the on switch.

**Insertion Loss**

The loss due to the on resistance of the switch.

**THD + N**

Ratio of the harmonics amplitude plus noise of a signal to the fundamental.

**T<sub>SKEW</sub>**

The measure of the variation in propagation delay between each channel.

## OUTLINE DIMENSIONS

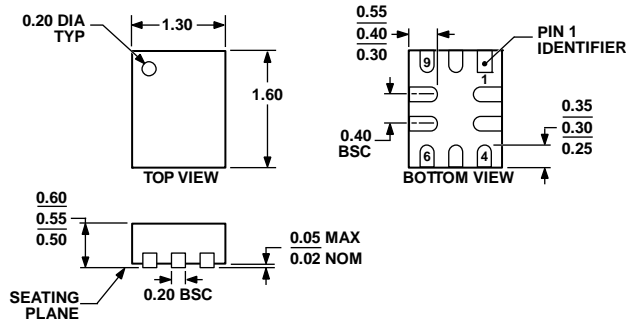
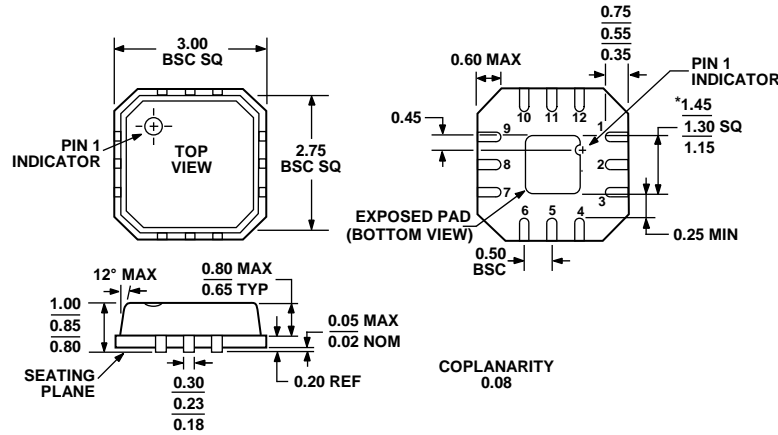


Figure 31. 10-Lead Mini Lead Frame Chip Scale Package [LFCSP\_UQ]  
1.30 mm × 1.60 mm Body, Ultra Thin Quad  
(CP-10-10)  
Dimensions shown in millimeters



\*COMPLIANT TO JEDEC STANDARDS MO-220-VEED-1 EXCEPT FOR EXPOSED PAD DIMENSION.

Figure 32. 12-Lead Lead Frame Chip Scale Package [LFCSP\_VQ]  
3 mm × 3 mm Body, Very Thin Quad  
(CP-12-1)  
Dimensions shown in millimeters

## ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option	Branding
ADG772BCPZ-1REEL <sup>1</sup>	-40°C to +85°C	12-Lead Lead Frame Chip Scale Package [LFCSP_VQ]	CP-12-1	S2P
ADG772BCPZ-REEL <sup>1</sup>	-40°C to +85°C	10-Lead Mini Lead Frame Chip Scale Package [LFCSP_UQ]	CP-10-10	B
ADG772BCPZ-REEL7 <sup>1</sup>	-40°C to +85°C	10-Lead Mini Lead Frame Chip Scale Package [LFCSP_UQ]	CP-10-10	B
EVAL-ADG772EBZ <sup>1</sup>	-40°C to +85°C	Evaluation Board		

<sup>1</sup> Z = RoHS Compliant Part.